TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

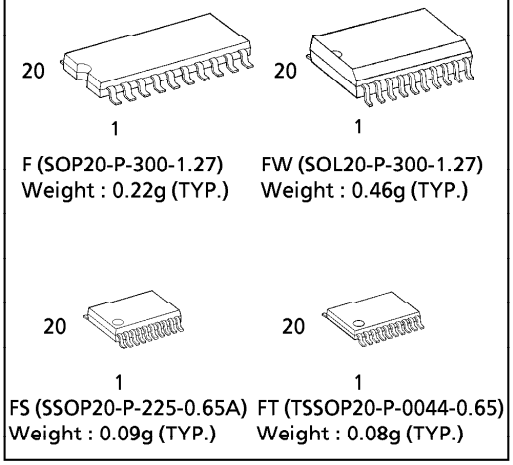
TC74VHC273F, TC74VHC273FW, TC74VHC273FS, TC74VHC273FT

OCTAL D-TYPE FLIP-FLOP WITH CLEAR

The TC74VHC273 is an advanced high speed CMOS OCTAL D-TYPE FLIP FLOP fabricated with silicon gate C^2MOS technology.
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.
Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.
When the $\overline{CLR}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.
An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

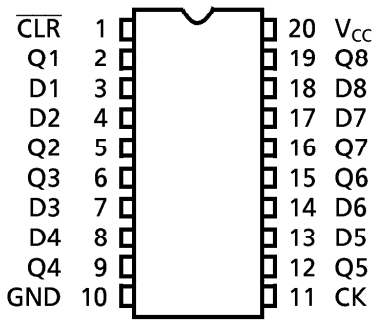
FEATURES:

- High Speed ····· f_{MAX} = 165MHz(typ.) at V_{CC} = 5V
- Low Power Dissipation ····· I_{CC} = 4μA(Max.)at Ta = 25°C
- High Noise Immunity ····· $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V~5.5V
- Low Noise ····· V_{OLP} = 0.9V (Max.)
- Pin and Function Compatible with 74ALS273



F (SOP20-P-300-1.27) Weight : 0.22g (TYP.)
FW (SOL20-P-300-1.27) Weight : 0.46g (TYP.)
FS (SSOP20-P-225-0.65A) Weight : 0.09g (TYP.)
FT (TSSOP20-P-0044-0.65) Weight : 0.08g (TYP.)

PIN ASSIGNMENT



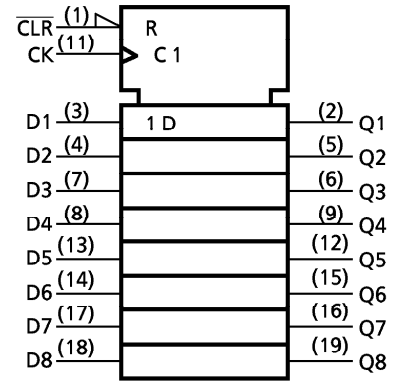
(TOP VIEW)

TRUTH TABLE

INPUTS			OUTPUT	FUNCTION
$\overline{CLR}$	D	CK	Q	
L	X	X	L	Clear
H	L	↑	L	—
H	H	↑	H	—
H	X	↓	Q_n	No change

X : Don't Care

IEC LOGIC SYMBOL



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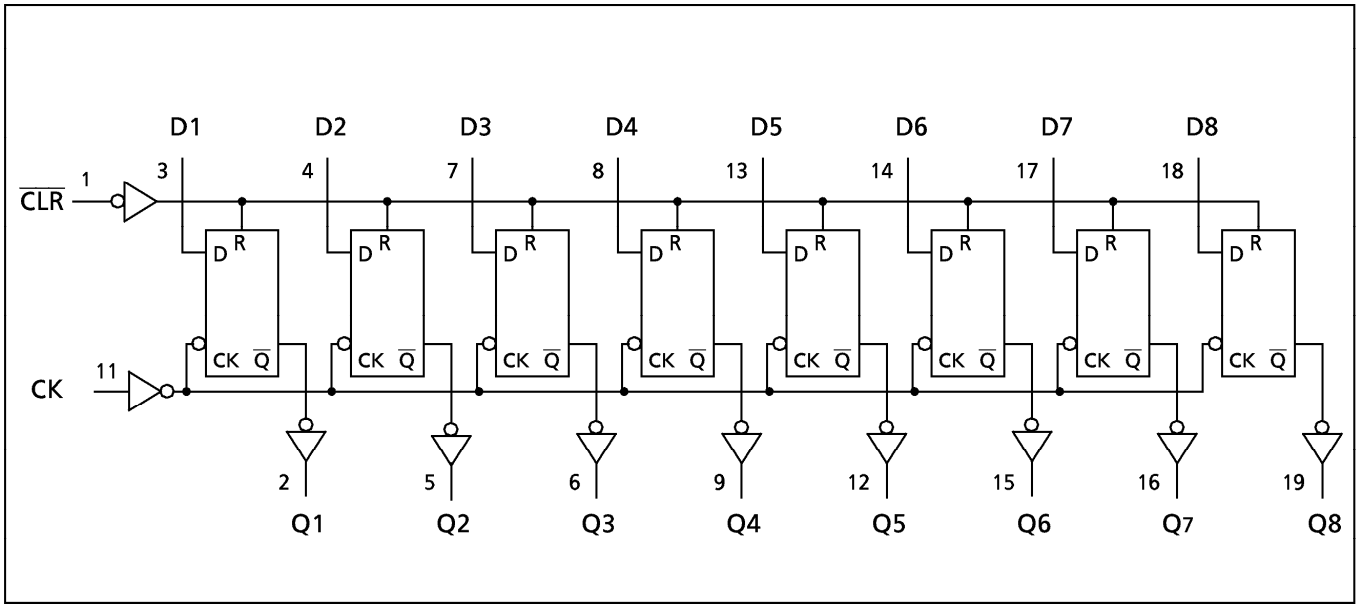
SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~7.0	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC}+0.5	V
Input Diode Current	I_{IK}	−20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	−65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dv	0~100 (V_{CC} = 3.3 ± 0.3V) 0~20 (V_{CC} = 5 ± 0.5V)	ns / V

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DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C			Ta = −40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}			2.0	1.50	—	—	1.50	—	V
				3.0~5.5	$V_{CC}\times0.7$	—	—	$V_{CC}\times0.7$	—	
Low - Level Input Voltage	V_{IL}			2.0	—	—	0.50	—	0.50	V
				3.0~5.5	—	—	$V_{CC}\times0.3$	—	$V_{CC}\times0.3$	
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I_{OH} = −4mA	3.0	2.58	—	—	2.48	—	
			I_{OH} = −8mA	4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I_{OL} = 4mA	3.0	—	—	0.36	—	0.44	
			I_{OL} = 8mA	4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	V_{IN} = 5.5V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f$ = 3ns)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C		Ta = −40~85°C	UNIT
				TYP .	LIMIT	LIMIT	
Minimum Pulse Width (CK)	$t_{W(L)}$		3.3 ± 0.3	—	5.5	6.5	ns
	$t_{W(H)}$		5.0 ± 0.5	—	5.0	5.0	
Minimum Pulse Width ($\overline{CLR}$)	$t_{W(L)}$		3.3 ± 0.3	—	5.0	6.0	
			5.0 ± 0.5	—	5.0	5.0	
Minimum Set - up Time	t_s		3.3 ± 0.3	—	5.5	6.5	
			5.0 ± 0.5	—	4.5	4.5	
Minimum Hold Time	t_h		3.3 ± 0.3	—	1.0	1.0	
			5.0 ± 0.5	—	1.0	1.0	
Minimum Removal Time ($\overline{CLR}$)	t_{rem}		3.3 ± 0.3	—	2.5	2.5	
			5.0 ± 0.5	—	2.0	2.0	

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION			Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK-Q)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	8.7	13.6	1.0	16.0	ns
				50	—	11.2	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.8	9.0	1.0	10.5	
				50	—	7.3	11.0	1.0	12.5	
Propagation Delay Time ($\overline{CLR}$-Q)	t_{pHL}		3.3 ± 0.3	15	—	8.9	13.6	1.0	16.0	
				50	—	11.4	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.2	8.5	1.0	10.0	
				50	—	6.7	10.5	1.0	12.0	
Maximum Clock Frequency	f_{MAX}		3.3 ± 0.3	15	75	120	—	65	—	MHZ
				50	50	75	—	45	—	
			5.0 ± 0.5	15	120	165	—	100	—	
				50	80	110	—	70	—	
Output to Output Skew	t_{osLH} t_{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input Capacitance	C_{IN}				—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 2)			—	31	—	—	—	

Note (1) Parameter guaranteed by design. $t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note (2) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per F/F)}$$

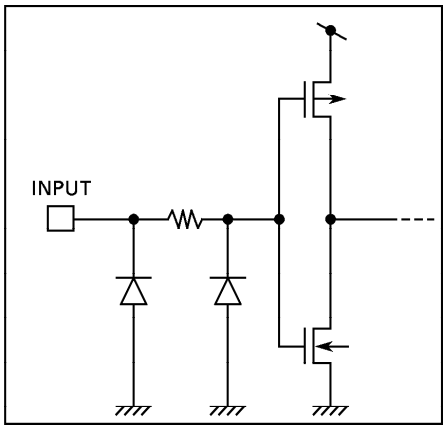
And the total C_{PD} when n pcs. of Flip Flop operate can be gained by the following equation:

$$C_{PD} \text{ (total)} = 22 + 9 \cdot n$$

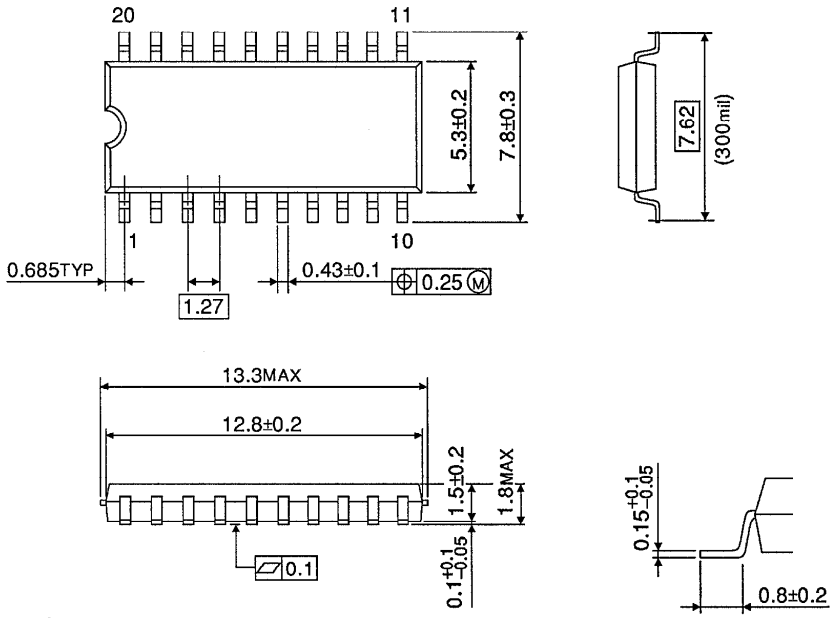
NOISE CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		UNIT
			V_{CC} (V)	TYP.	MAX.	
Quiet Output Maximum Dynamic V_{OL}	V_{OLP}	C_L = 50pF	5.0	0.6	0.9	V
Quiet Output Minimum Dynamic V_{OL}	V_{OLV}	C_L = 50pF	5.0	−0.6	−0.9	V
Minimum High Level Dynamic Input Voltage	V_{IHD}	C_L = 50pF	5.0	—	3.5	V
Maximum Low Level Dynamic Input Voltage	V_{ILD}	C_L = 50pF	5.0	—	1.5	V

INPUT EQUIVALENT CIRCUIT

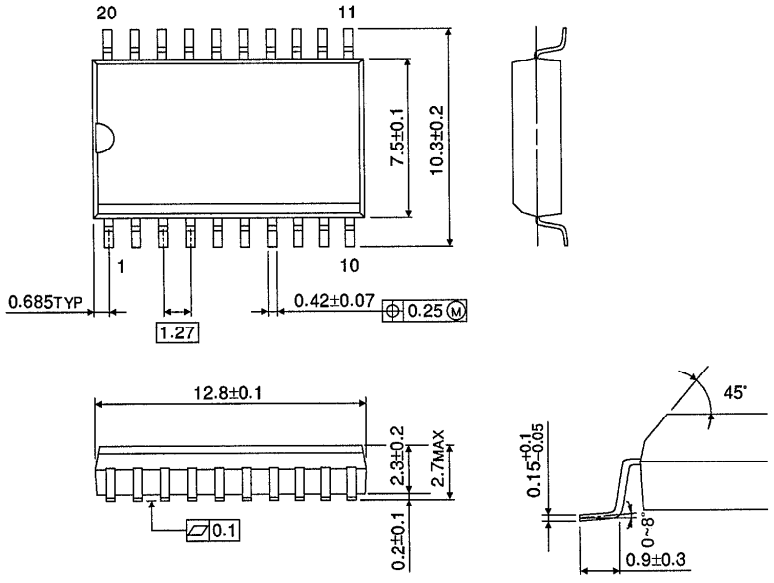


SOP 20PIN (200mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27) Unit in mm



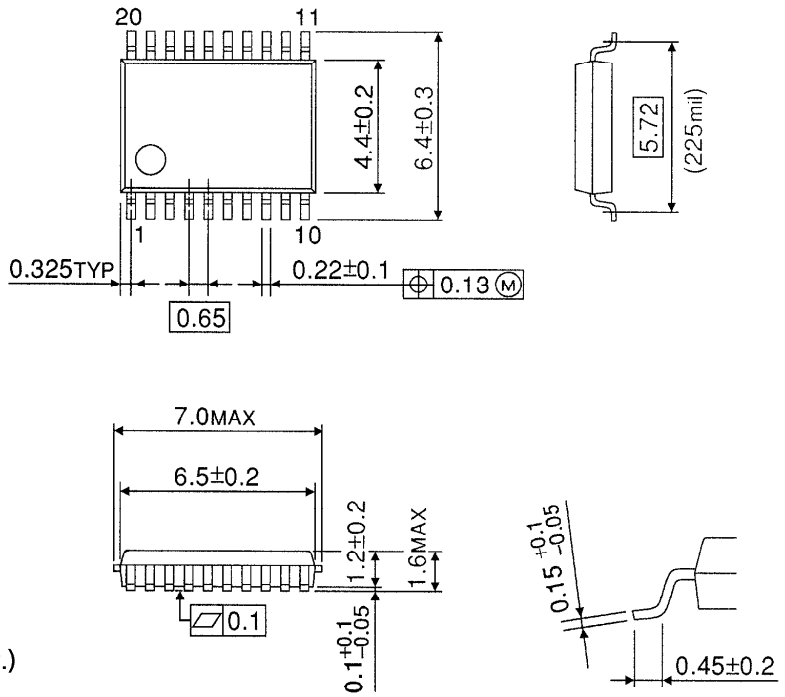
Weight : 0.22g (TYP.)

SOP 20PIN (300mil BODY) OUTLINE DRAWING (SOL20-P-300-1.27) Unit in mm



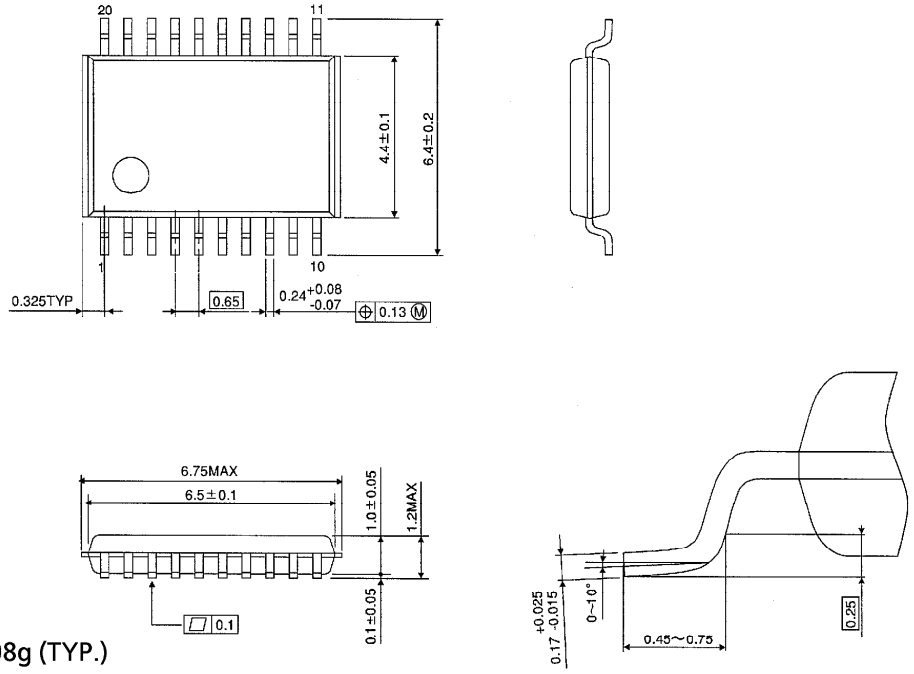
Weight : 0.46g (TYP.)

SSOP 20PIN OUTLINE DRAWING (SSOP20-P-225-0.65A) Unit in mm



Weight : 0.09g (TYP.)

TSSOP 20PIN OUTLINE DRAWING (TSSOP20-P-0044-0.65) Unit in mm



Weight : 0.08g (TYP.)